



High Efficiency Standard Rectifier

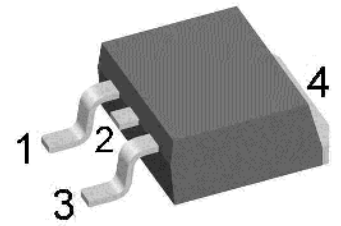
$V_{RRM} = 800\text{ V}$
 $I_{FAV} = 40\text{ A}$
 $V_F = 1.26\text{ V}$

Single Diode

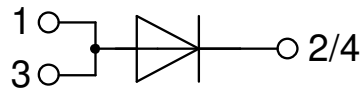
Part number

DLA40IM800PC

Marking on Product: *DLA40IM800PC*



Backside: cathode



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

Applications:

- Diode for main rectification
- For single and three phase bridge configurations

Package: TO-263 (D2Pak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

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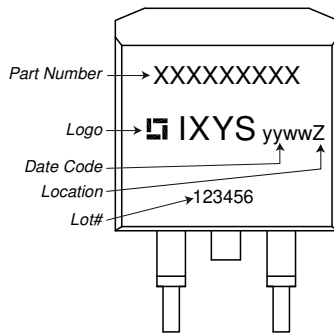
Rectifier				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
V_{RSM}	max. non-repetitive reverse blocking voltage				900	V	
V_{RRM}	max. repetitive reverse blocking voltage				800	V	
I_R	reverse current	$V_R = 800\text{ V}$			10	μA	
		$V_R = 800\text{ V}$			0.05	mA	
V_F	forward voltage drop	$I_F = 40\text{ A}$			1.30	V	
		$I_F = 80\text{ A}$			1.56	V	
		$I_F = 40\text{ A}$	$T_{VJ} = 150^\circ\text{C}$			1.26	V
		$I_F = 80\text{ A}$	$T_{VJ} = 150^\circ\text{C}$			1.65	V
I_{FAV}	average forward current	$T_C = 120^\circ\text{C}$ rectangular			40	A	
V_{FO}	threshold voltage	} for power loss calculation only			0.85	V	
r_F	slope resistance				10	m Ω	
R_{thJC}	thermal resistance junction to case				0.8	K/W	
R_{thCH}	thermal resistance case to heatsink			0.25		K/W	
P_{tot}	total power dissipation		$T_C = 25^\circ\text{C}$		185	W	
I_{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^\circ\text{C}$		300	A	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0\text{ V}$		325	A	
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 150^\circ\text{C}$		255	A	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0\text{ V}$		275	A	
I^2t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^\circ\text{C}$		450	A ² s	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0\text{ V}$		440	A ² s	
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 150^\circ\text{C}$		325	A ² s	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0\text{ V}$		315	A ² s	
C_J	junction capacitance	$V_R = 400\text{ V}; f = 1\text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$		10	pF	



Package TO-263 (D2Pak)			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal ¹⁾			35	A
T_{VJ}	virtual junction temperature		-55		175	°C
T_{op}	operation temperature		-55		150	°C
T_{stg}	storage temperature		-55		150	°C
Weight				1.5		g
F_C	mounting force with clip		20		60	N

¹⁾ I_{RMS} is typically limited by the pin-to-chip resistance (1); or by the current capability of the chip (2). In case of (1) and a product with multiple pins for one chip-potential, the current capability can be increased by connecting the pins as one contact.

Product Marking



Part description

- D = Diode
- L = Low Voltage Standard Rectifier
- A = (up to 1200V)
- 40 = Current Rating [A]
- IM = Single Diode
- 800 = Reverse Voltage [V]
- PC = TO-263AB (D2Pak) (2)

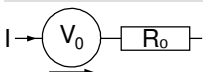
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DLA40IM800PC-TRL	DLA40IM800PC	Tape & Reel	800	509995
Alternative	DLA40IM800PC-TUB	DLA40IM800PC	Tube	50	525085

Similar Part	Package	Voltage class
DSI30-08AS	TO-263AB (D2Pak) (2)	800
DSI30-12AS	TO-263AB (D2Pak) (2)	1200
DSI30-16AS	TO-263AB (D2Pak) (2)	1600

Equivalent Circuits for Simulation

** on die level*

$T_{VJ} = 175^{\circ}C$

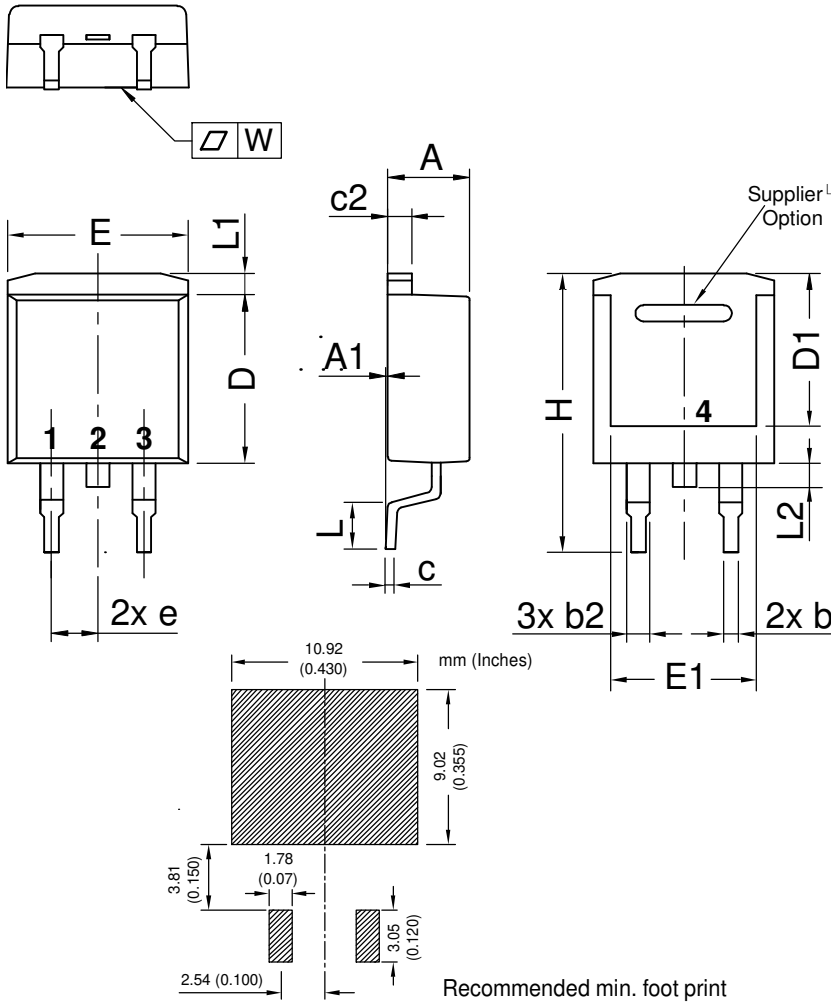


Rectifier

$V_{0\ max}$	threshold voltage	0.85	V
$R_{0\ max}$	slope resistance *	6.8	mΩ

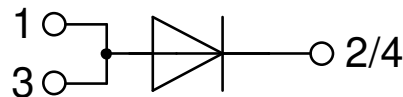


Outlines TO-263 (D2Pak)



Dim.	Millimeter		Inches	
	min	max	min	max
A	4.06	4.83	0.160	0.190
A1	typ. 0.10		typ. 0.004	
A2	2.41		0.095	
b	0.51	0.99	0.020	0.039
b2	1.14	1.40	0.045	0.055
c	0.40	0.74	0.016	0.029
c2	1.14	1.40	0.045	0.055
D	8.38	9.40	0.330	0.370
D1	8.00	8.89	0.315	0.350
D2	2.5		0.098	
E	9.65	10.41	0.380	0.410
E1	6.22	8.50	0.245	0.335
e	2,54 BSC		0,100 BSC	
e1	4.28		0.169	
H	14.61	15.88	0.575	0.625
L	1.78	2.79	0.070	0.110
L1	1.02	1.68	0.040	0.066
W	typ. 0.02	0.040	typ. 0.0008	0.002

All dimensions conform with and/or within JEDEC standard.





Rectifier

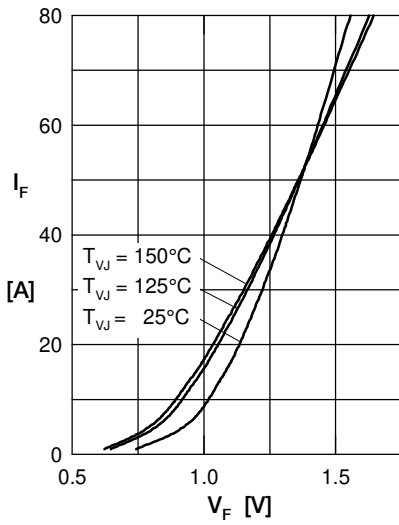


Fig. 1 Forward current versus voltage drop

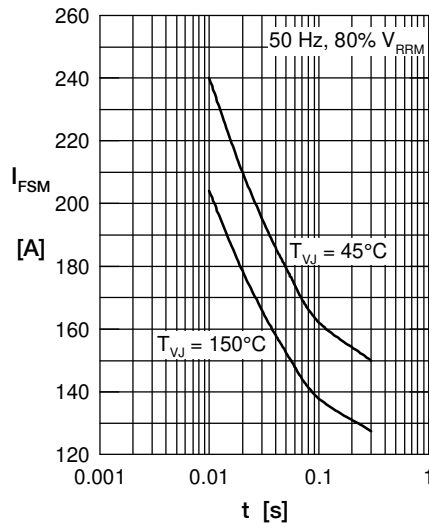


Fig. 2 Surge overload current

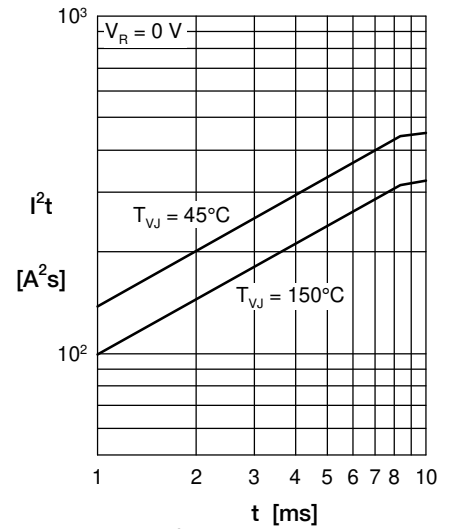


Fig. 3 I^2t versus time

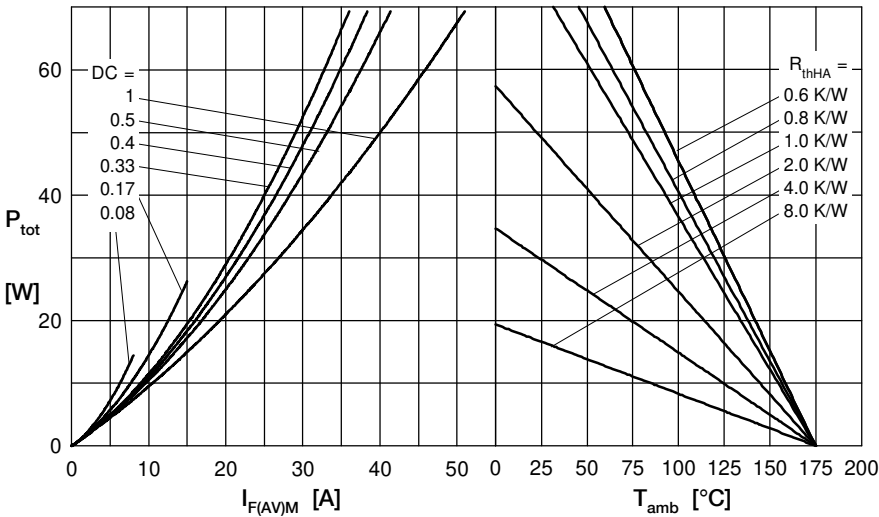


Fig. 4 Power dissipation versus direct output current and ambient temperature

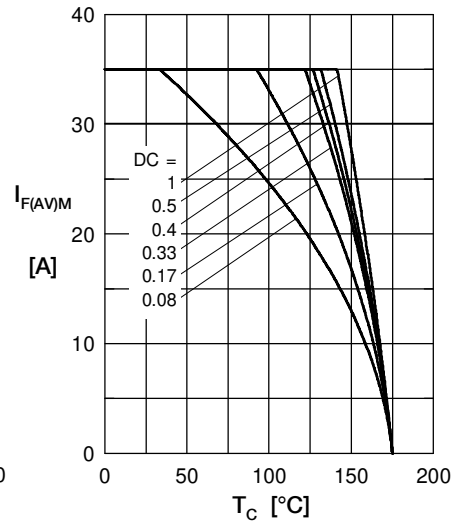


Fig. 5 Max. forward current vs. case temperature

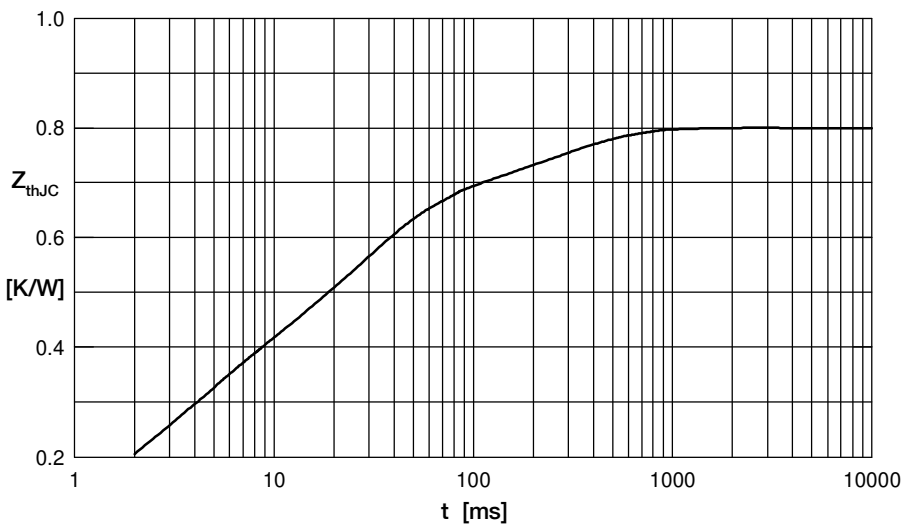


Fig. 6 Transient thermal impedance junction to case

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.04	0.0004
2	0.07	0.002
3	0.19	0.003
4	0.35	0.024
5	0.15	0.25